



EVERLIGHT ELECTRONICS CO., LTD.

DATA SHEET

MODEL NO	:	PD93-21C
DATE	:	JUN ,27, 2000
DEPARTMENT	:	R&D 2
REVISION	:	1.0

RECEIVED			
☒ MASS PRODUCTION			
☐ PRELIMINARY			
☐ CUSTOMER DESIGN			
DEVICE NUMBER : DPD-093-069			
PAGE :7			
CUSTOMER	DESIGNER	CHECKER	APPROVER

REV	DESCRIPTION	RELEASE DATE

OFFICE:..NO.25,LANE76,SEC.3,CHUNG YANG RD.,TUCHENG 236,TAIPEI,TAIWAN,R.O.C

TEL : 886-2-22672000,2267-9936

FAX : 886-2-22676244,22676189,22676306

<http://www.everlight.com>



Top Silicon PIN Photodiode

MODEL NO : PD93-21C

■ Features :

- Fast response time
- High photo sensitivity
- Small junction capacitance

■ Description :

PD93-21C is a PIN photodiode in miniature SMD package which is molded in a water clear with flat top view lens. The device is spectrally matched to infrared emitting diode.

■ Applications :

- High speed photo detector
- Camera
- Infrared applied system
- Optoelectronic switch
- Floppy disk drive

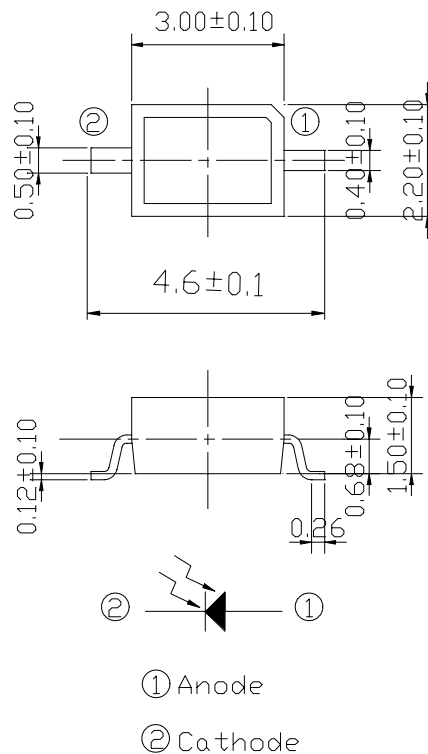
PART NO.	CHIP	LENS COLOR
	MATERIAL	
PD	Silicon	Water Clear



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■ Package Dimensions :



■ Notes :

1. All dimensions are in millimeter.
2. General Tolerance: ± 0.1 mm
3. Lens color : Water clear.
4. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
5. These specification sheets include materials protected under copyright of EVERLIGHT corporation . Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent.
6. When using this product , please observe the absolute maximum ratings and the instructions for use outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.



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■ Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Rating	Unit	Notice
Reverse Voltage	V_R	32	V	
Power Dissipation	P_d	150	mW	
Lead Soldering Temperature	T_{sol}	260	°C	
Operating Temperature	T_{opr}	-25 ~ +85	°C	
Storage Temperature	T_{stg}	-40 ~ +85	°C	

■ Electronic Optical Characteristics :

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Rang of Spectral Bandwidth	$\lambda_{0.5}$	----	400-1200	----	nm	-----
Wavelength of Peak Sensitivity	λ_p	----	980	----	nm	-----
Open-Circuit Voltage	V_{OC}	----	0.42	----	V	Ee=5m W/c m ² λ_p =940nm
Short-Circuit Current	I_{SC}	----	4.5	----	μA	
Reverse Light Current	I_L	----	4.5	----	μA	Ee=5m W/c m ² λ_p =940nm V_R =5V
Dark Current	I_d	----	----	10	nA	Ee=0m W/c m ² V_R =10V
Reverse Breakdown Voltage	BV_R	32	170	----	V	Ee=0m W/c m ² I_R =100μA
Total Capacitance	C_t	----	5	----	pF	Ee=0m W/c m ² V_R =5V, f=1MHz
Rise/Fall Time	t_r/t_f	----	6/6	----	nS	V_R =10V R_L =1KΩ



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■ Typical Electrical/Optical/Characteristics Curves

Fig. 1 Power Dissipation vs.
Ambient Temperature

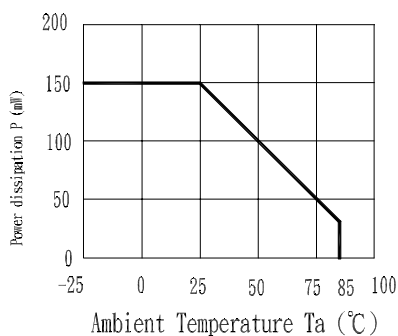


Fig. 2 Spectral Sensitivity

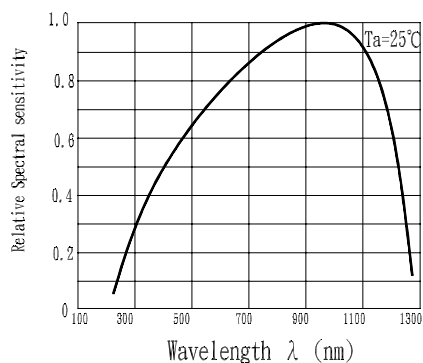


Fig. 3 Dark Current vs.
Ambient Temperature

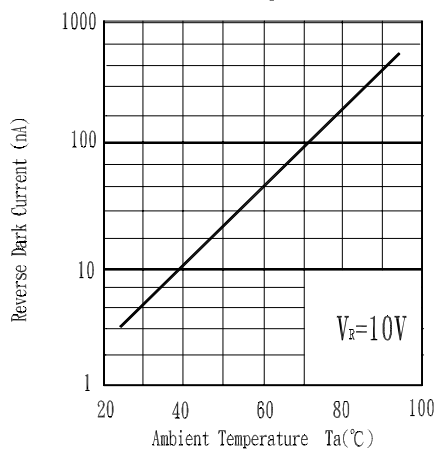


Fig. 4 Reverse Light Current vs. E_e

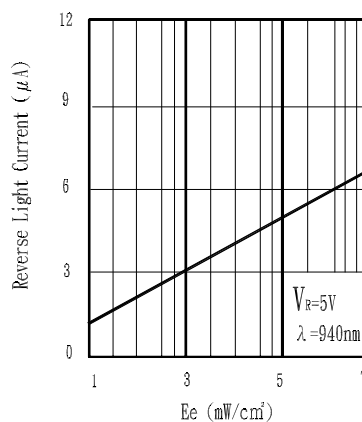


Fig. 5 Terminal Capacitance vs.
Reverse Voltage

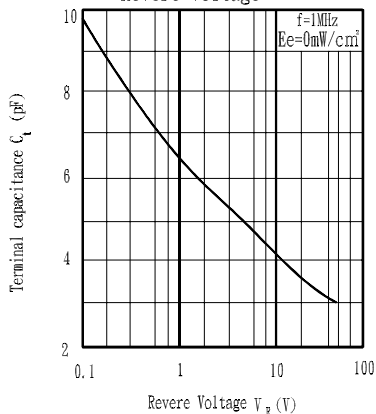
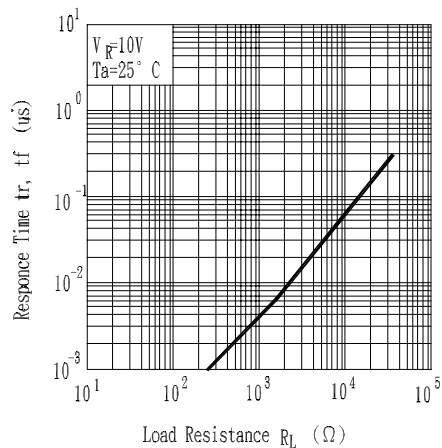


Fig. 6 Responce Time vs.
Load Resistance





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■ Reliability Test Item And Condition

The reliability of products shall be satisfied with items listed below.

Confidence level:90%

LTPD:10%

NO.	Item	Test Conditions	Test Hours/ Cycles	Sample Size	Failure Judgement Criteria	Ac/Re
1	REFLOW	TEMP : 240℃ ± 5 °C 5 secs	6 Mins	22 pcs	More than 90% of lead to be covered by soldering	0/1
2	Temperature Cycle	H : +85℃ 30 mins 5 mins L : -55℃ 30 mins	50 cycles	22 pcs	$I_L \leq L \times 0.8$ L :Lower specification limit	0/1
3	Thermal Shock	H : +100℃ 5 mins 10 secs L : -10℃ 5 mins	50 cycles	22 pcs		0/1
4	High Temperature Storage	TEMP. : +100℃	1000 hrs	22 pcs		0/1
5	Low Temperature Storage	TEMP. : -55℃	1000 hrs	22 pcs		0/1
6	DC Operating Life	V _R =5V	1000 hrs	22 pcs		0/1
7	High Temperature / High Humidity	85℃ / 85% R.H.	1000 hrs	22 pcs		0/1



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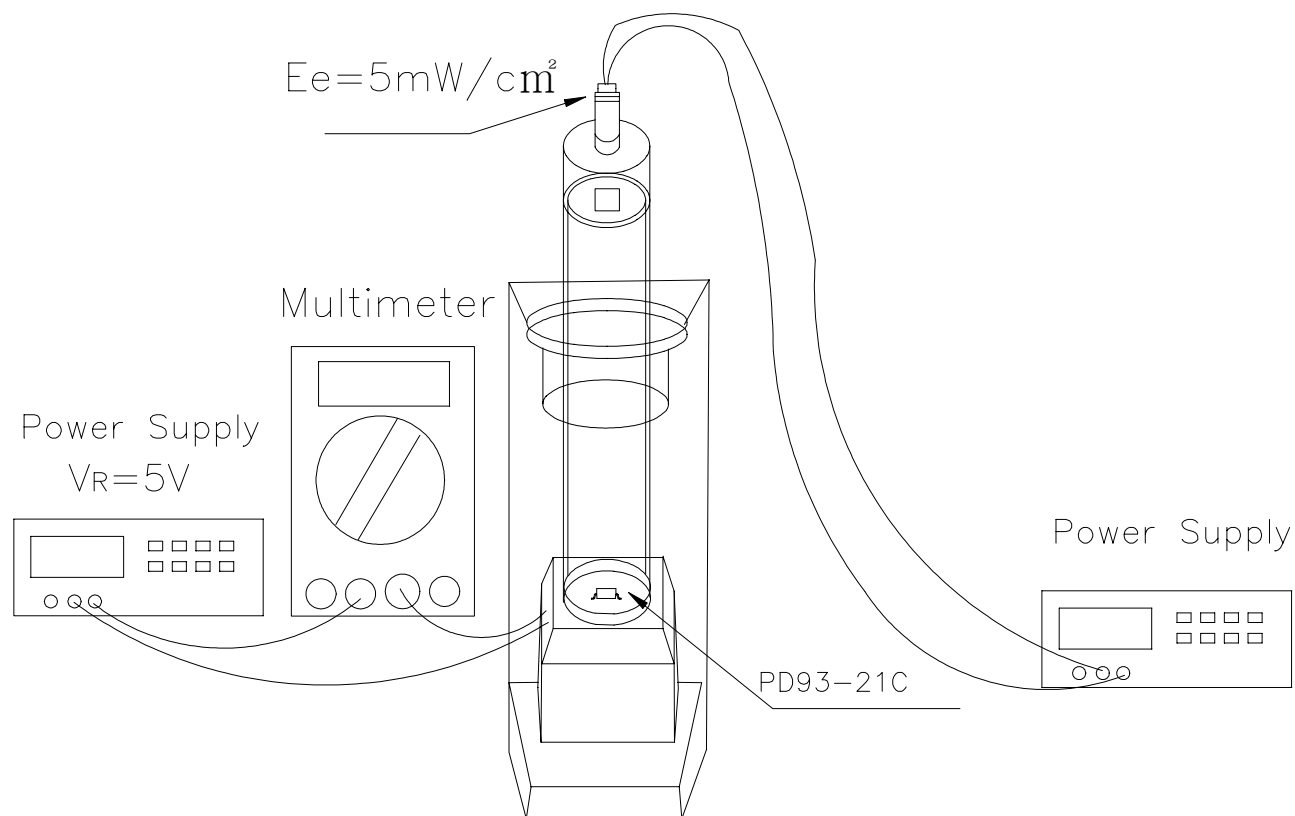
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■ Test Method For Reverse Light Current

Condition: $E_e=5\text{mW}/\text{cm}^2$, $V_R=5\text{V}$

Test Item: Reverse Light Current

Unit : μA





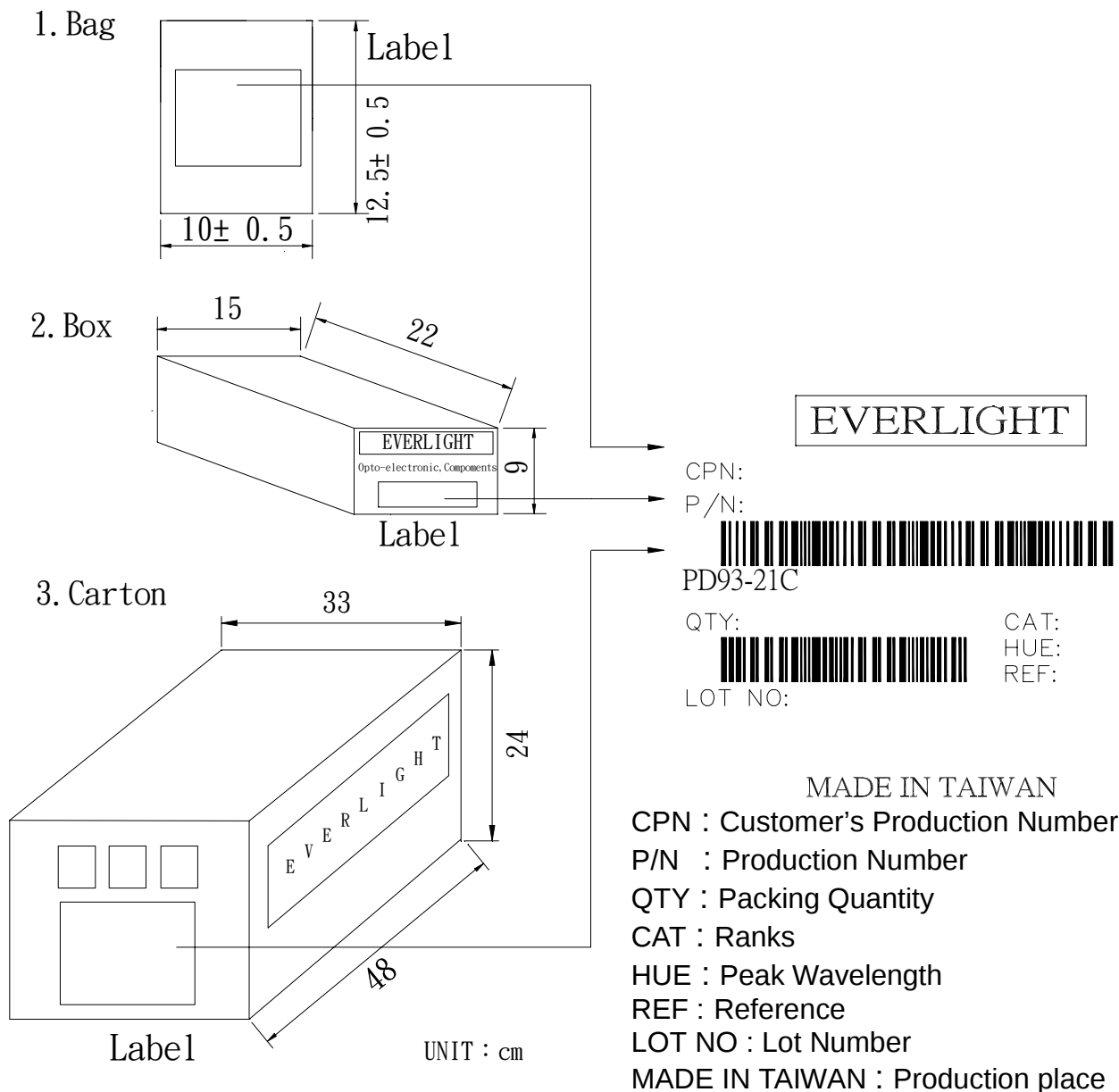
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■ Packing Specifications



■ Packing Quantity Specification

1. 1000 Pcs/1Bag , 20 Bags/1Box
2. 10 Boxes/1Carton